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APPLICATION NO.		FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/657,841	10/657,841 09/09/2003		Johannes Baur	P2001,0176	2117		
24131	7590	09/22/2004		EXAMINER			
		EENBERG, PA	MULPURI, SAVITRI				
P O BOX 24 HOLLYWO		33022-2480	ART UNIT	PAPER NUMBER			
				2812			
				DATE MAILED: 09/22/200	DATE MAILED: 09/22/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicat	ion No.	Applicant(s)					
Office Action Summary			341	BAUR ET AL.					
			er	Art Unit					
		Savitri N	1ulpuri	2812					
	The MAILING DATE of this commu	nication appears on th	e cover sheet with the	correspondence ad	ldress				
Period fo	, ,								
THE - Exte after - If the - If NO - Failt Any	ORTENED STATUTORY PERIOD MAILING DATE OF THIS COMMUN misions of time may be available under the provision SIX (6) MONTHS from the mailing date of this come period for reply specified above is less than thirty of period for reply is specified above, the maximum is ure to reply within the set or extended period for repreply received by the Office later than three months led patent term adjustment. See 37 CFR 1.704(b).	NICATION. ns of 37 CFR 1.136(a). In no enterior in the standard in the standa	event, however, may a reply be tireattory minimum of thirty (30) day will expire SIX (6) MONTHS from optication to become ABANDONE	nely filed vs will be considered timel the mailing date of this c ED (35 U.S.C. § 133).					
Status									
· 1)⊠	Responsive to communication(s) fi	led on 22 June 2004							
2a)□	Responsive to communication(s) filed on <u>22 June 2004</u> . This action is FINAL . 2b)⊠ This action is non-final.								
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is								
<u>ا</u> رت	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.								
	·	and and an panto a	,,,		`				
Disposit	ion of Claims								
4)⊠	Claim(s) <u>1-26</u> is/are pending in the application.								
	4a) Of the above claim(s) is/are withdrawn from consideration. 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) <u>1-6 and 8-25</u> is/are rejected.								
5)[
6)⊠									
7)⊠	Claim(s) <u>7 and 26</u> is/are objected to.								
8)[Claim(s) are subject to restriction and/or election requirement.								
Applicat	ion Papers								
9)[The specification is objected to by t	he Examiner.							
10)	☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.								
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11)[The oath or declaration is objected	to by the Examiner. N	Note the attached Office	Action or form P	TO-152.				
Priority	under 35 U.S.C. § 119				,				
-	Acknowledgment is made of a clain	n for foroign priority u	ndor 35 II S C & 110/o) (d) or (f)					
<i>'</i> —	☐ All b)☐ Some * c)☐ None of:)-(a) or (i).					
	1. Certified copies of the priorit	•		N					
	2. Certified copies of the priorit	*			l Ctoo				
	3. Copies of the certified copies	• •		ed in this National	Stage				
*	application from the Internat			ad					
,	See the attached detailed Office acti	ion for a list of the cer	tilled copies flot receive	su.					
Attachmei	nt(s)								
_	ce of References Cited (PTO-892)		4) Interview Summary	/ (PTO-413)					
2) Noti	ce of Draftsperson's Patent Drawing Review		Paper No(s)/Mail D	ate	O 152)				
	mation Disclosure Statement(s) (PTO-1449 or er No(s)/Mail Date	or PTO/SB/08)	5) Notice of Informal I	-атепт Арріісатіоп (РТ	U-132)				

DETAILED ACTION

This action is in response to the applicant's communication filed on 6 6/22/2004.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1-6, 8- 25are rejected under 35 U.S.C. 102(e) as being anticipated by Eisert et al (US 6,730,939).

Eisert et al teaches a radiation-emitting semiconductor component comprising: epitaxial multilayer structure including active layer for generating radiation in multilayer structure, electrical contacts connected to said active layer, radiation. Tran missive window "20" with first main surface and adjoining multilayer structure and second main surface opposite said first main surface and second main surface having at least one void selected from the group consisting of a trench recess and a pit recess formed therein for increasing coupling out of radiation from said window, wherein window have side surface "20 a,20b" and having partial regions perpendicular and orthogonal to first and second main surfaces respectively; and said window has an enveloping basic shape selected from the group consisting of parallelized or cuboid shapes; void has at least one planar side surface enclosing an angle different from 90

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degrees with second main surface, wherein void is a trench recess formed with triangular or trapezoidal cross section tapering towards the first surface (see fig. 1a, 1b, 1c, 3 a and related description). Eisert et al teaches window contains silicon carbide material and multilayer structure is GaN based compound with elements comprising Al, In and or Ga, wherein window material layer higher refractive index than that of multi layer structure (see col.9, lines 35-46). Eisert et al teaches void is bounded by at least one curved surface and void has cone shape (see 8-11). Eisert et al teaches wafer bonding or epiaxial growth (see col.2, lines 4-13). Eisert et al teaches sawing technique to form trench recess by saw blade "80" having trapezoidal cross section (see col. 14, lines 52-67, and col. 15, lines 1-20). Eisert et al teaches etching the recess (see col. 11, lines 5-8).

Claim 7,26 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Applicant's arguments with respect to claims 1-26 have been considered but are most in view of the new ground(s) of rejection.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Savitri Mulpuri whose telephone number is 571-272-1677. The examiner can normally be reached on Mon-Fri from 8 a.m. to 4.30 p.m.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling, can be reached on 571-272-1677. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Application/Control Number: 10/657,841

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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